

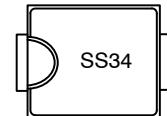
SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER



Cathode — Anode

DO-214AB (SMC)

MARKING DIAGRAMS



PRODUCT SUMMARY	
Package	SMC
$I_{F(AV)}$	3.0 A
V_R	40 V
V_F at I_F	0.43 V
I_{RM} max.	35 mA at 125 °C
T_J max.	150 °C
Diode variation	Single die
E_{AS}	6.0 mJ

ORDERING INFORMATION

Device	Package	Shipping [†]
SS34	SMC (Pb-Free)	3000 / Tape & Reel

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	3.0	A
V_{RRM}		40	V
I_{FSM}	$t_p = 5 \mu s$ sine	1580	A
V_F	3.0 A _{pk} , $T_J = 125^\circ C$	0.43	V
T_J	Range	-55 to +150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-MBRS340-M3	UNITS
Maximum DC reverse voltage	V_R	40	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_L = 118^\circ C$, rectangular waveform		3.0	A	
		50 % duty cycle at $T_L = 110^\circ C$, rectangular waveform		4.0		
Maximum peak one cycle non-repetitive surge current	I_{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	1580		
		10 ms sine or 6 ms rect. pulse		80		
Non-repetitive avalanche energy	E_{AS}	$T_J = 25^\circ C$, $I_{AS} = 1.0 A$, $L = 12 mH$		6	mJ	
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		1.0	A	

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop	$V_{FM}^{(1)}$	3 A	$T_J = 25 \text{ }^\circ\text{C}$	0.525	V	
		6 A		0.68		
		3 A	$T_J = 125 \text{ }^\circ\text{C}$	0.43		
		6 A		0.57		
Maximum reverse leakage current	$I_{RM}^{(1)}$	$T_J = 25 \text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	2.0	mA	
		$T_J = 100 \text{ }^\circ\text{C}$		20		
		$T_J = 125 \text{ }^\circ\text{C}$		35		
Maximum junction capacitance	C_T	$V_R = 5 \text{ V}_{\text{DC}}$ (test signal range 100 kHz to 1 MHz), $25 \text{ }^\circ\text{C}$		230	pF	
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		3.0	nH	
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s	

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}, T_{Stg}$			-55 to +150	${}^\circ\text{C}$
Maximum thermal resistance, junction to lead	$R_{thJL}^{(2)}$	DC operation		12	${}^\circ\text{C/W}$
Maximum thermal resistance, junction to ambient	R_{thJA}			46	
Approximate weight				0.24	g
				0.008	oz.
Marking device		Case style SMC (similar to DO-214AB)		34	

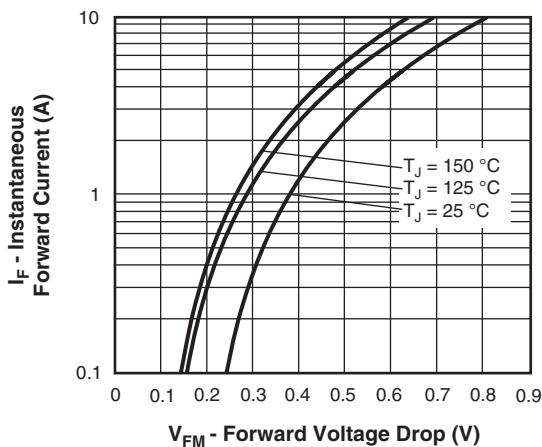


Fig. 1 - Maximum Forward Voltage Drop Characteristics
(Per Leg)

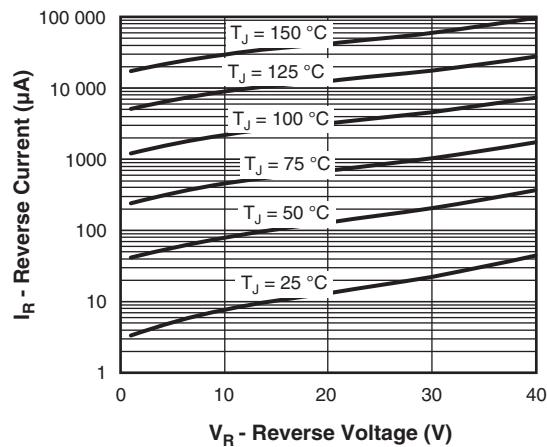


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage
(Per Leg)

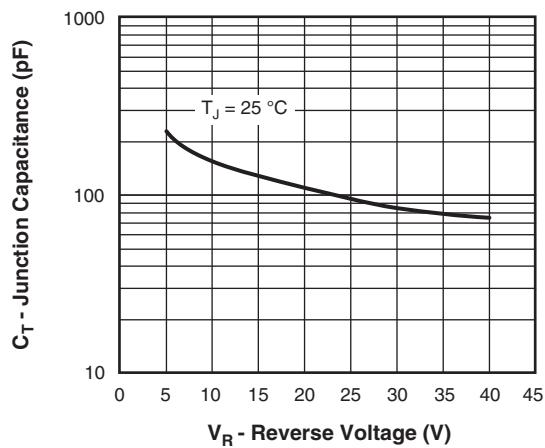


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

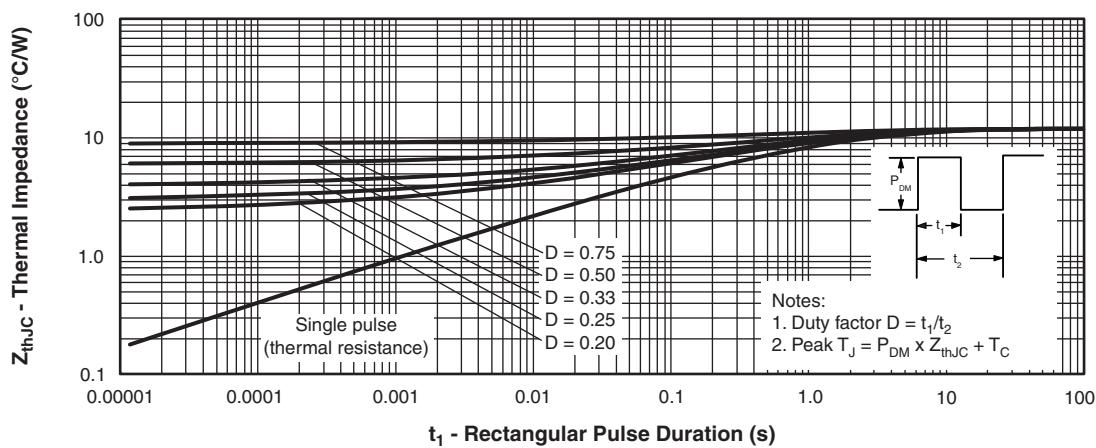


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

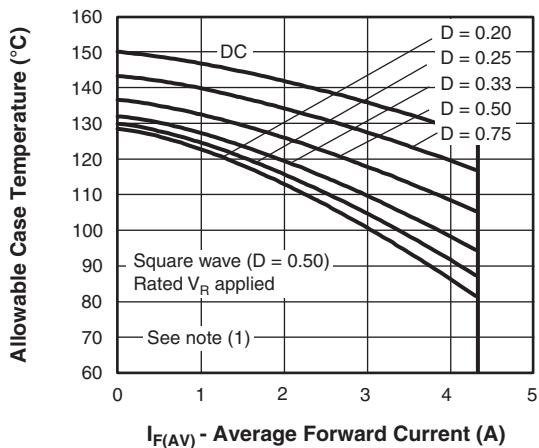


Fig. 5 - Maximum Average Forward Current vs.
Allowable Lead Temperature

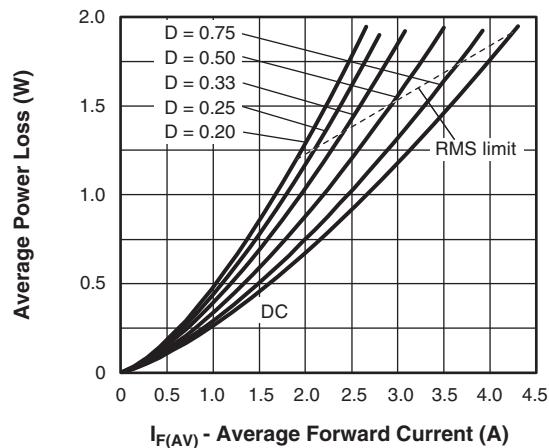


Fig. 6 - Maximum Average Forward Dissipation vs.
Average Forward Current

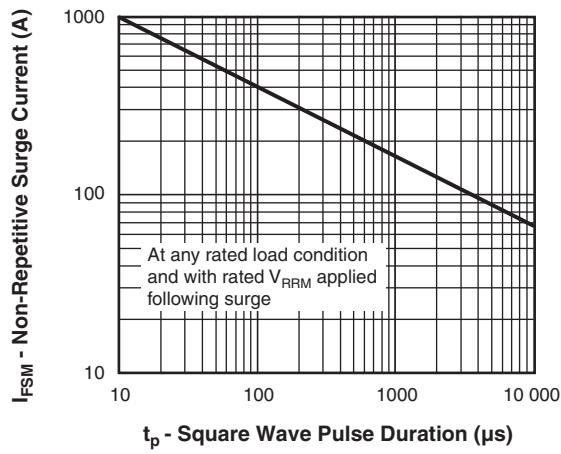
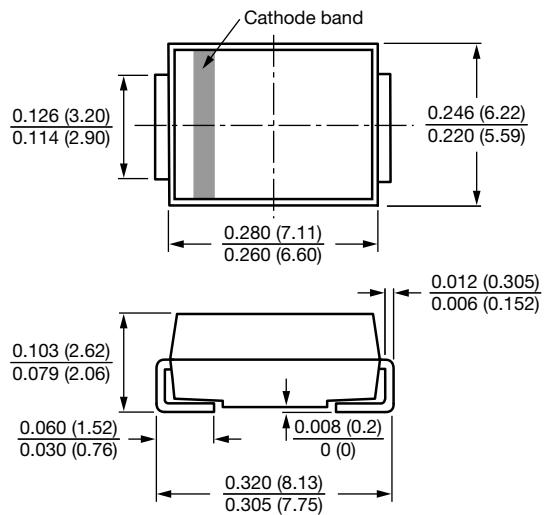


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

DIMENSIONS in inches (millimeters)

DO-214AB (SMC)

Mounting Pad Layout
